ABSTRACT OF THE DISCLOSURE

The present invention provides a positive photoresist composition for far ultraviolet exposure, which comprises a polymer having at least one of a repeating unit represented by formula (Ia) and a repeating unit represented by formula (Ib), and a repeating unit represented by formula (II), and having a group capable of decomposing by the action of an acid:

wherein R_1 and R_2 each represents hydrogen atom, a cyano group, a hydroxyl group, -COOH, -COOR₅, -CO-NH-R₆, -CO-NH-SO₂-R₆, an alkyl group, an alkoxy group, a cyclic hydrocarbon group or a -Y group, X represents -O-, -S-, -NH-, -NHSO₂- or -NHSO₂NH-, A represents a single bond or a divalent linking group, Z_2 represents -O- or -N(R_3)-, R_{11} and R_{12} each represents a hydrogen atom, a cyano group, a halogen atom or an alkyl group, Z_1 represents an atomic group necessary for forming an alicyclic structure which contains two bonded carbon atoms (C-C), and Y, R_3 , R_5 and R_6 are as defined in the specification.